# NSN 5962-01-273-4267

Memory Microcircuit - Page 1 of 1



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# **Operating Tempurature Range:**

+0.0/+70.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## Features Provided:

Programmed and 3-state output and high impedance and w/enable and monolithic

## Inclosure Material:

Ceramic or plastic

## Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Transistor-transistor logic

## Input Circuit Pattern:

14 input

#### Current Rating Per Characteristic:

185.00 milliamperes reverse current, dc absolute

#### **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 7.0 volts power source

#### **Time Rating Per Chacteristic:**

100.00 nanoseconds access

## Memory Device Type:

Prom

#### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### **Terminal Type And Quantity:**

24 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

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### Demilitarization:

Yes - demil/mli

Fiig:

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